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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): MAMITSU et al.	Atty. Dkt.: 01-103-CON1
Serial No.: 10/699,828	Group Art Unit: 2811
Filed: November 4, 2003	Examiner: Unknown
Title: <b>SEMICONDUCTOR DEVICE HAVING RADIATION STRUCTURE</b>	



Commissioner for Patents  
Arlington, VA 22202

Date: October 14, 2004

**INFORMATION DISCLOSURE STATEMENT**

Sir:

Pursuant to 37 C.F.R. §1.56, the references listed on the attached Form PTO-1449 are being submitted for consideration by the Examiner without any admission that they constitute statutory prior art, or without any admission that they contain subject matter that anticipates the invention or renders the invention obvious to a person of ordinary skill in the art.

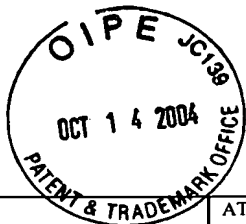
Further, pursuant to 37 C.F.R. §1.97(e)(1), the undersigned hereby certifies that each listed reference was first cited in a Communication (copy enclosed) from a foreign patent office in connection with a counterpart foreign application not more than three months prior to the filing of this statement.

Although no fees are believed to be due at this time, it is respectfully requested that any such fees be charged to Deposit Account 50-1147. Also, the Examiner is requested to initial the attached PTO Form-1449 and to return a copy of same to the undersigned attorney as proof that the listed references have been considered and made of record.

Respectfully submitted,

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**PATENT APPLICATION**  
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FORM PTO-1449	ATTY. DKT NO.	01-103-CON1	SER. NO.	10/699,828
	APPLICANT <b>MAMITSU et al.</b>			
	FILING DATE	November 4, 2003	GROUP	2811

**REFERENCE DESIGNATION**

**U.S. PATENT DOCUMENTS**

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS

**FOREIGN PATENT DOCUMENTS**

								TRANSLATION	
		DOCUMENT NUMBER	DATE	COUNTRY	NAME	CLASS	SUB CLASS	YES	NO (Abstract)
		JP-A-H07-66143	3/10/95	JAPAN					X
		JP-A-H09-237868	9/9/97	JAPAN					X
		JP-A-H09-45773	2/14/97	JAPAN					X
		JP-A-H11-204803	7/30/99	JAPAN					X

\* Full English text of the JP Document will be available in machine-translated form from JP (Japanese Patent Office) English language web site at <http://www1.ipdl.jpo.go.jp/PA1/cgi-bin/PA1INDEX>.

**OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)**

EXAMINER		DATE CONSIDERED